

# iscN-Channel MOSFET Transistor

## **TK12A50D**

#### • FEATURES

- Low drain-source on-resistance:  $R_{DS}(ON) = 0.52\Omega$  (MAX)
- Enhancement mode:Vth = 2 to 4V (VDS = 10 V, ID=1.0mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



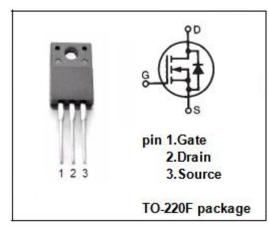
· Switching Voltage Regulators

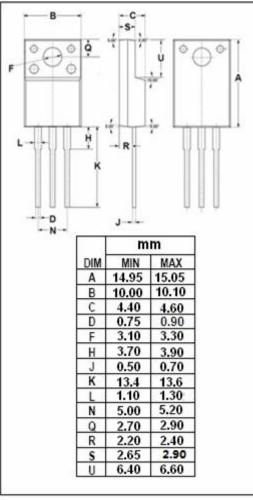
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	500	V
V <sub>G</sub> s	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous	12	А
I <sub>DM</sub>	Drain Current-Single Pulsed	48	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C 45		W
Tj	Max. Operating Junction Temperature 150		$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature -55~150		${\mathbb C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.78	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =6A			520	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =500V; V <sub>GS</sub> = 0V			10	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =12A, V <sub>GS</sub> = 0 V			1.7	V



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